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July 2016



RGF1A - RGF1M Fast Rectifiers

Features

- Glass Passivated Junction
- For Surface Mounted Application
- Low Forward Voltage Drop
- High Current Capability
- Easy Pick and Place
- High Surge Current Capability



Ordering Information

Part Number	Top Mark	Package	Packing Method
RGF1A	RGF1A	DO-214AC (SMA)	Tape and Reel
RGF1B	RGF1B	DO-214AC (SMA)	Tape and Reel
RGF1D	RGF1D	DO-214AC (SMA)	Tape and Reel
RGF1G	RGF1G	DO-214AC (SMA)	Tape and Reel
RGF1J	RGF1J	DO-214AC (SMA)	Tape and Reel
RGF1K	RGF1K	DO-214AC (SMA)	Tape and Reel
RGF1M	RGF1M	DO-214AC (SMA)	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol		Value								
	Parameter	RGF1 A	RGF1 B	RGF1 D	RGF1 G	RGF1 J	RGF1 K	RGF1 M	Unit	
V _{RRM}	Maximum Repetitive Reverse Voltage	50	100	200	400	600	800	1000	V	
I _{F(AV)}	Average Rectified Forward Current at $T_L = 125^{\circ}C$	1.0								
I _{FSM}	Non-Repetitive Peak Forward Surge Current: 8.3 ms Single Half-Sine Wave	ne 30							A	
T _{STG}	Storage Temperature Range -65 to +175				5			°C		
TJ	Operating Junction Temperature	-65 to +175								

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Thermal Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
PD	Power Dissipation	1.76	W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient ⁽¹⁾	85	°C/W
$R_{ ext{ heta}JL}$	Thermal Resistance, Junction-to-Lead ⁽¹⁾	28	°C/W

Note:

1. Device mounted on FR-4 PCB 0.013 mm.

Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

	Parameter			Value								
Symbol		Conditions		RGF1 A	R	GF1 B	RGF1 D	RGF1 G	RGF1 J	RGF1 K	RGF1 M	Unit
V _F	Forward Voltage	I _F = 1.0 A						1.3				V
t _{rr}	Reverse Recovery Time	I _F = 0.5 A, I _R I _{rr} = 0.25 A	= 1.0 A,			15	50		250	50	00	ns
1-	Reverse Current			5.0								
IR	at Rated V _R	T _A = 125°C			100						μA	
CT	Total Capacitance	V _R = 4.0 V, f = 1.0 MHz						8.5				pF

RGF1A - RGF1M — Fast Rectifiers

Typical Performance Characteristics

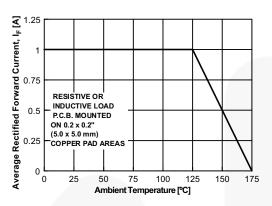


Figure 1. Forward Current Derating Curve

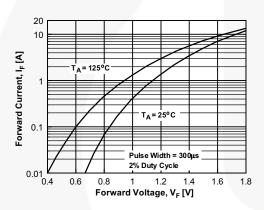


Figure 3. Foward Voltage Characteristics

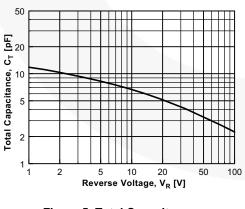


Figure 5. Total Capacitance

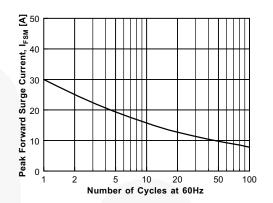


Figure 2. Non-Repetitive Surge Current

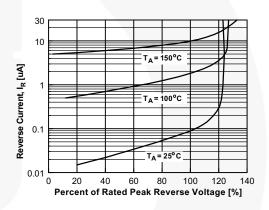
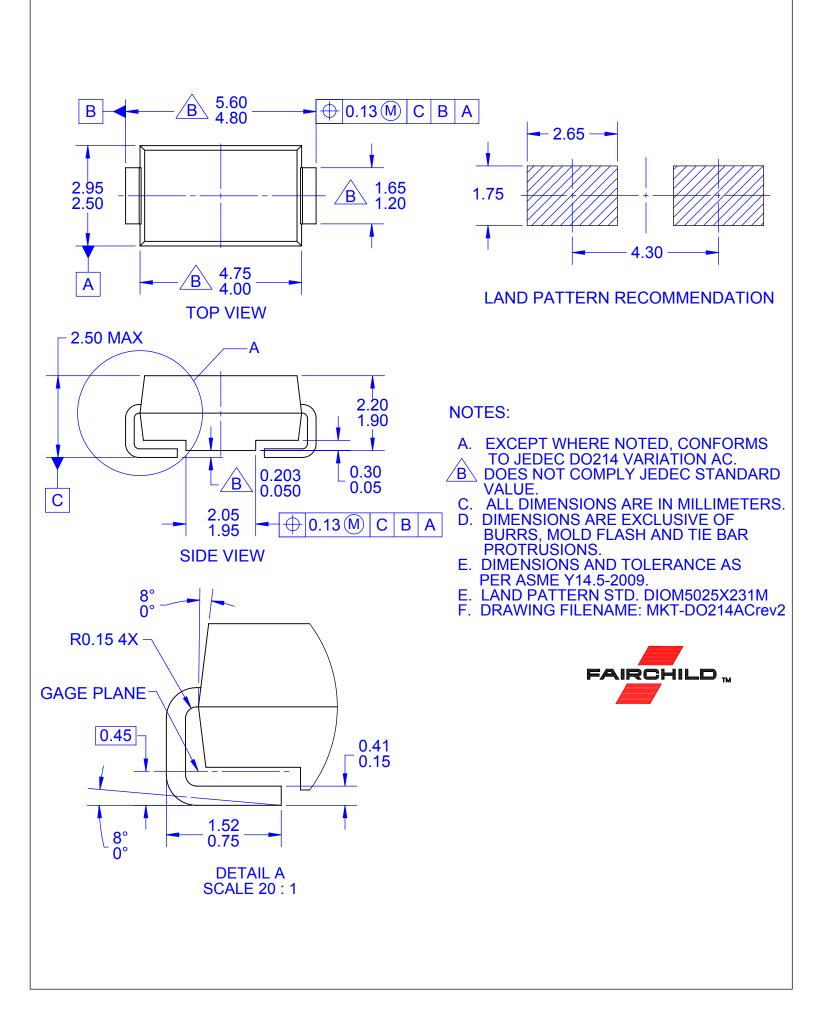


Figure 4. Reverse Current vs. Reverse Voltage

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